

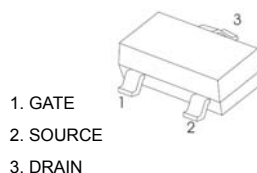
FEATURES

- High density cell design for low $R_{DS(ON)}$
- Voltage controlled small signal switch
- Rugged and reliable
- High saturation current capability

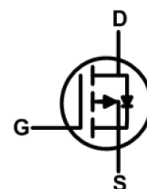
V_{DSS} -30 V
 I_D -4.2 A
 $R_{DS(ON)}$ 41 m Ω

A19T

SOT-23



Equivalent Circuit



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Limit	Unit
V_{DS}	Drain-Source Voltage	-30	V
V_{GS}	Gate-Source Voltage	± 12	V
I_D	Drain Current-Continuous	-4.2	A
I_{DM}	Drain Current-Pulsed (Note 1)	-30	A
P_D	Maximum Power Dissipation	1.2	W
T_J, T_{STG}	Operating Junction and Storage Temperature Range	-55 To 150	$^\circ\text{C}$
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient (Note 2)	104	$^\circ\text{C/W}$

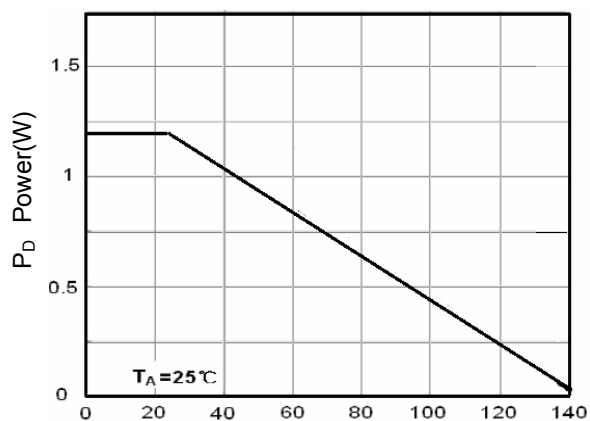
Electrical Characteristics (TA=25°C unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Off characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = -250\mu A$	-30			V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = -24V, V_{GS} = 0V$			-1	μA
Gate-source leakage current	I_{GSS}	$V_{GS} = \pm 12V, V_{DS} = 0V$			± 100	nA
On characteristics						
Drain-source on-resistance (note 1)	$R_{DS(on)}$	$V_{GS} = -10V, I_D = -4.2A$		41	60	m Ω
		$V_{GS} = -4.5V, I_D = -4A$		47	70	m Ω
		$V_{GS} = -2.5V, I_D = -1A$		61	85	m Ω
Forward tranconductance (note 1)	g_{FS}	$V_{DS} = -5V, I_D = -5A$	7			S
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-0.7		-1.3	V
Dynamic characteristics (note 2)						
Input capacitance	C_{iss}	$V_{DS} = -15V, V_{GS} = 0V, f = 1MHz$		1050		pF
Output capacitance	C_{oss}			127		pF
Reverse transfer capacitance	C_{rss}			85		pF
Switching characteristics (note 2)						
Turn-on delay time	$t_{d(on)}$	$V_{GS} = -10V, V_{DS} = -15V,$ $R_L = 3.6\Omega, R_{GEN} = 6\Omega$			6.5	ns
Turn-on rise time	t_r				3.5	ns
Turn-off delay time	$t_{d(off)}$				40	ns
Turn-off fall Time	t_f				13	ns
Drain-source diode characteristics and maximum ratings						
Diode forward voltage (note 1)	V_{SD}	$I_S = -1A, V_{GS} = 0V$			-1	V

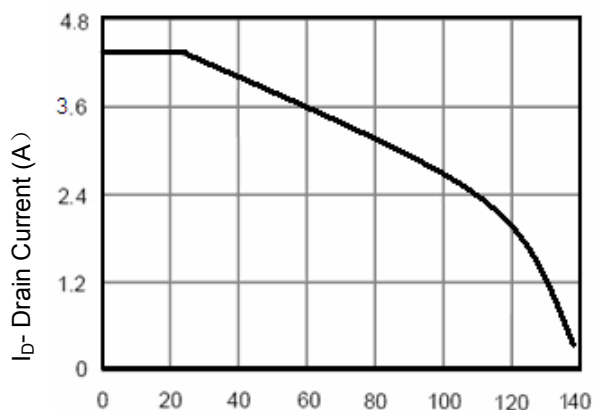
Note :

1. Pulse Test : Pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.
2. These parameters have no way to verify.

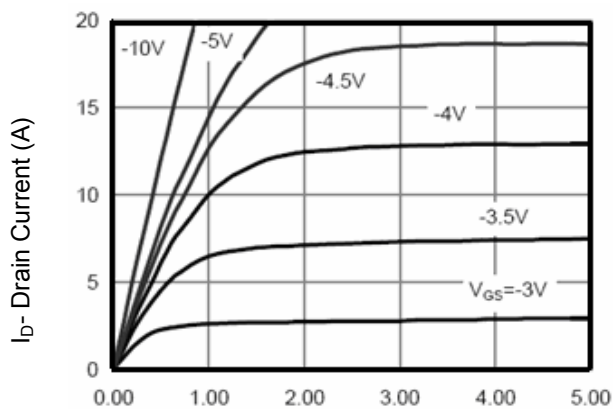
RATING AND CHARACTERISTIC CURVES



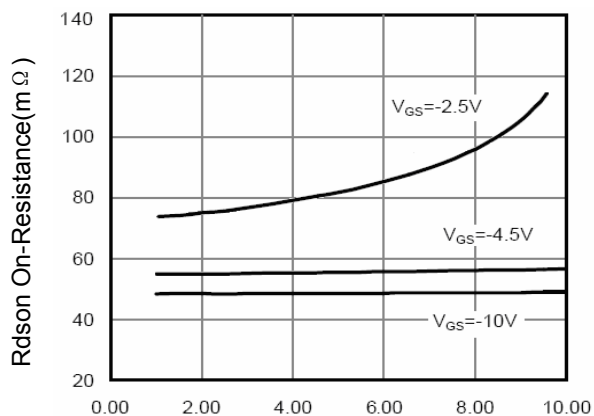
T_J -Junction Temperature($^{\circ}C$)
Figure 1 Power Dissipation



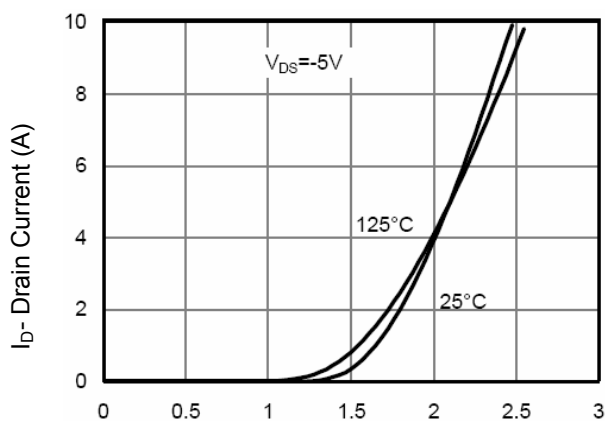
T_J -Junction Temperature($^{\circ}C$)
Figure 2 Drain Current



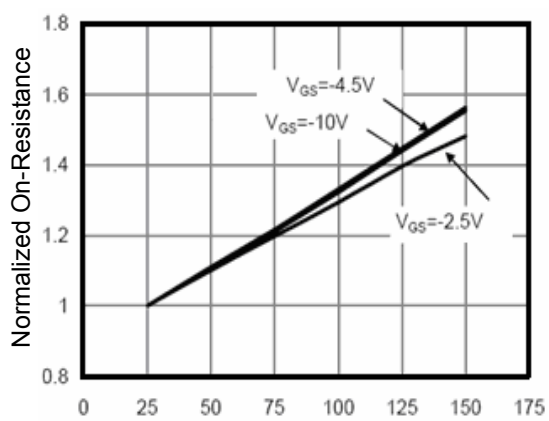
V_{DS} Drain-Source Voltage (V)
Figure 3 Output Characteristics



I_D - Drain Current (A)
Figure 4 Drain-Source On-Resistance

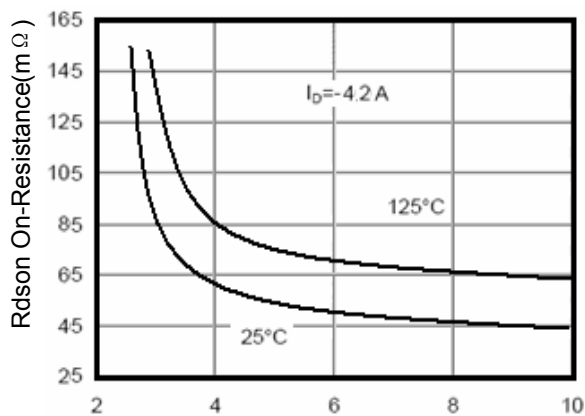


V_{GS} Gate-Source Voltage (V)
Figure 5 Transfer Characteristics

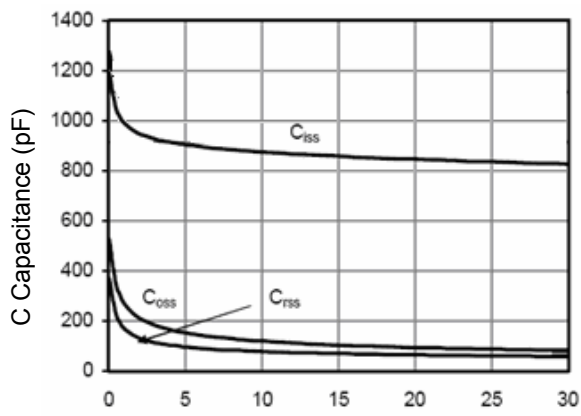


T_J -Junction Temperature($^{\circ}C$)
Figure 6 Drain-Source On-Resistance

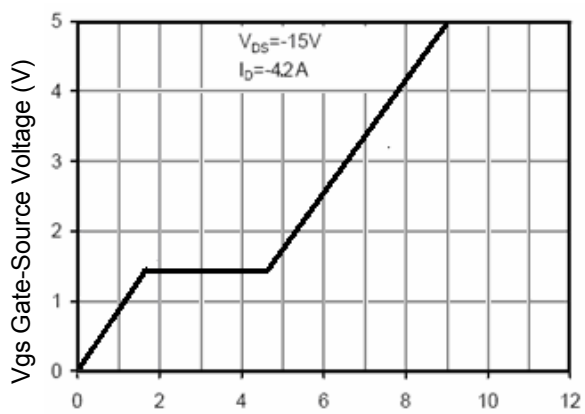
RATING AND CHARACTERISTIC CURVES



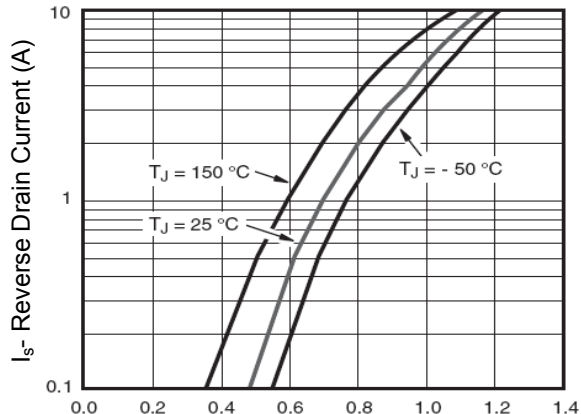
Vgs Gate-Source Voltage (V)
Figure 7 Rdson vs Vgs



Vds Drain-Source Voltage (V)
Figure 8 Capacitance vs Vds



Qg Gate Charge (nC)
Figure 9 Gate Charge



Vsd Source-Drain Voltage (V)
Figure 10 Source- Drain Diode Forward

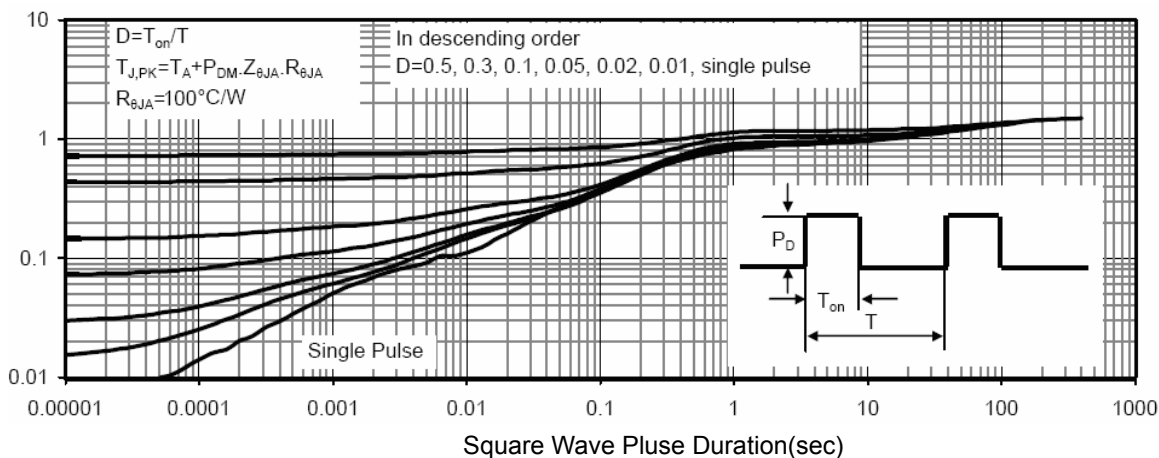
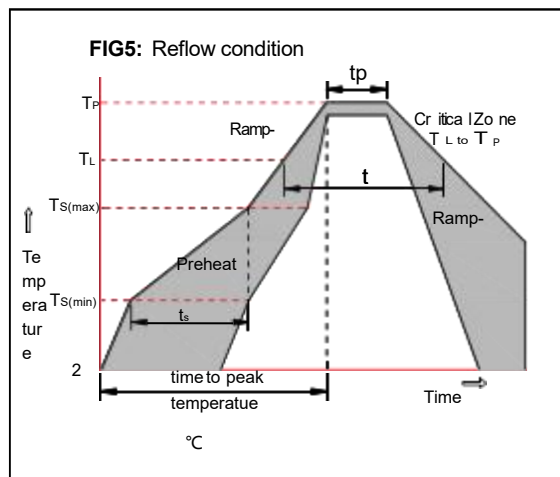


Figure 14 Normalized Maximum Transient Thermal Impedance

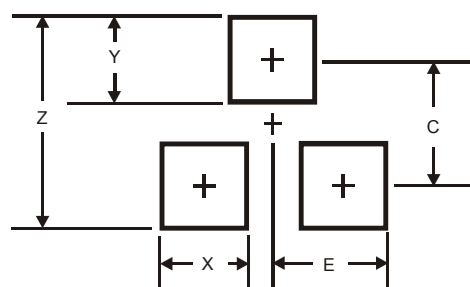
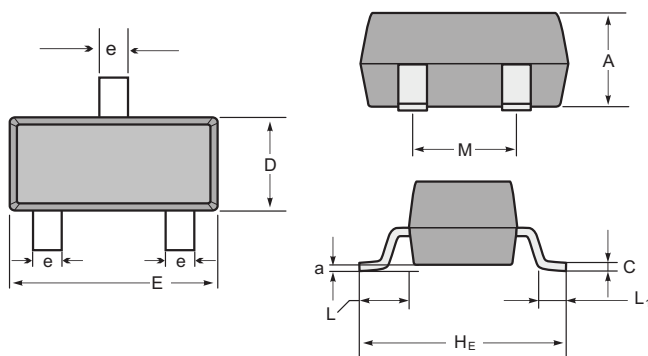
Soldering parameters

Reflow Condition		Pb-Free assembly (see as below)
Pre Heat	-Temperature Min ($T_{s(min)}$)	+150°C
	-Temperature Max($T_{s(max)}$)	+200°C
	-Time (Min to Max) (ts)	60-180 secs.
Average ramp up rate (Liquid us Temp (T_L) to peak)		3°C/sec. Max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/sec. Max
Reflow	-Temperature(T_L)(Liquid us)	+217°C
	-Temperature(t_L)	60-150 secs.
Peak Temp (T_P)		+260(+0/-5)°C
Time within 5°C of actual Peak Temp (t_P)		30 secs. Max
Ramp-down Rate		6°C/sec. Max
Time 25°C to Peak Temp (T_P)		8 min. Max
Do not exceed		+260°C



Package Dimensions & Suggested Pad Layout

SOT23

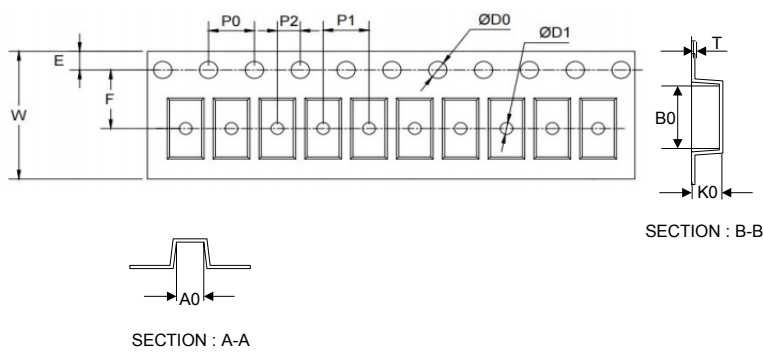
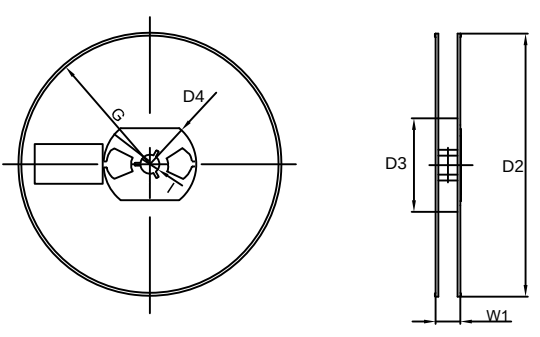


SOT-23 mechanical data

UNIT		A	C	D	E	H _E	e	M	L	L ₁	a
mm	max	1.1	0.15	1.4	3.0	2.6	0.5	1.95	0.55 (ref)	0.36 (ref)	0.0
	min	0.9	0.08	1.2	2.8	2.2	0.3	1.7			0.15
mil	max	43	6	55	118	102	20	77	22 (ref)	14 (ref)	0.0
	min	35	3	47	110	87	12	67			6

Dimensions	SOT23
Z	2.9
X	0.8
Y	0.9
C	2.0
E	1.35

Tape & reel specification

Tape 	Symbol	Dimension (mm)
	P0	4.00±0.10
	P1	4.00±0.10
	P2	2.00±0.10
	D0	1.55±0.10
	D1	1.05±0.10
	E	1.55±0.10
	F	3.60±0.10
	W	8.00±0.10
	A0	3.80±0.20
	B0	3.25±0.20
	K0	1.45±0.10
	T	0.25±0.05
	D2	178.0±3.0
7" Reel 	D3	55Min.
	D4	R24.0±3.0
	G	R82.0±3.0
	I	13.0±2.0
	W1	11.0±3.0
	Quantity: 3000PCS	